University of Mumbai

Program: Electronics Engineering Curriculum Scheme: Rev 2016 Examination: BE Semester VII

Course Code: ELX702 Time: 2 hour 30 minutes

_

Course Name: Power Electronics Max. Marks: 80

Q1.	Choose the correct option for following questions. All the Questions are compulsory and carry equal marks
1.	The DIAC can be represented by
Option A:	two SCRs in anti-parallel
Option B:	two SCRs in parallel
Option C:	two diodes in anti-parallel
Option D:	two diodes in parallel
2.	The TRIAC can be represented by
Option A:	two SCRs in anti-parallel
Option B:	two SCRs in parallel
Option C:	two diodes in anti-parallel
Option D:	two diodes in parallel
3.	The TRIAC's terminals are
Option A:	gate, anode, cathode
Option B:	MT1, MT2, gate
Option C:	gate1, gate2, anode, cathode
Option D:	MT1, MT2, gate1, gate2
4.	A power transistor is a
Option A:	three layer, three junction device
Option B:	three layer, two junction device
Option C:	two layer, one junction device
Option D:	four layer, three junction device
5.	Choose the correct statement
Option A:	MOSFET is a uncontrolled device
Option B:	MOSFET is a voltage controlled device
Option C:	MOSFET is a current controlled device
Option D:	MOSFET is a temperature controlled device
6.	A thyristor (SCR) is a
Option A:	P-N-P device
Option B:	N-P-N device
Option C:	P-N-P-N device
Option D:	P-N device

7.	In the SCR structure the gate terminal is located
Option A:	near the anode terminal
Option B:	near the cathode terminal
Option C:	in between the anode & cathode terminal
Option D:	none of the mentioned
8.	A thyristor can be bought from the forward conduction mode to forward blocking
	mode by
Option A:	the dv/dt triggering method
Option B:	applying a negative gate signal
Option C:	applying a positive gate signal
Option D:	applying a reverse voltage across anode-cathode terminals
9.	For the SCR to remain in the ON (conducting) state
Option A:	gate signal is continuously required
Option B:	no continuous gate signal is required
Option C:	no forward anode-cathode voltage is required
Option D:	negative gate signal is continuously required
10.	The average output voltage of single phase half-wave is maximum when SCR is
	triggered at $\omega t =$
Option A:	Π
Option B:	0
Option C:	π/2
Option D:	π/4

Q2	Solve any Four out of Six5 marks each
А	Describe different modes of operation of SCR with the help its static V-I characteristics and explain what is holding current and latching current.
В	Explain single phase full-bridge inverter with R load.
С	Explain with the help of neat circuit diagram and waveforms what the effect of freewheeling diode is on the performance of single phase half wave controlled rectifier with RL load.
D	What are turn on methods of SCR? What are the basic requirements for successful turn on of SCR? Which is the best method of SCR triggering explain why?
E	Describe the principle of on-off control and phase control.
F	Write a short note on Single phase cyclo-converter

Q3.	Solve any Two Questions out of Three	10 marks each
А	Draw the schematic of step-up and step-down choppers and derive an expression for output voltage in terms of duty cycle for a step-up and stepdown chopper.	

В	Discuss the effect of source inductance on the performance of single phase fully controlled converter, indicating clearly the conduction of various thyristors during one cycle.
С	Draw and explain the basic series inverter circuit employing class A type commutation. Draw and discuss the important waveforms. State the limitations of this series inverter.

Q4.	Solve any Two Questions out of Three	10 marks each	
А	Draw ramp and pedestal trigger circuit used for single phase semi converter. Describe its operation with appropriate waveforms		
В	A single phase fully controlled bridge converter supplies an inductive load. Assuming that the output current is virtually constant and is equal to Id, determine the following performance measures, if the supply voltage is equal to 230 V and if the firing angle is maintained at ($\pi/6$) radians. (i) Average output voltage (ii) Supply RMS current (iii) Supply fundamental RMS current (iv) Fundamental power factor (v) Supply power factor (vi) Supply harmonic factor (vii) Voltage ripple factor		
С	Write a short note oni)Battery charging systemsii)Static characteristics of IGBT		